

# GD54/74HC540, GD54/74HCT540 OCTAL INVERTING 3-STATE BUFFERS

## General Description

These devices are identical in pinout to the 54/74LS540. These eight inverting buffers feature two NORed active-low output enables, inverting 3-state outputs, and inputs and outputs on opposite sides of the package. These octal inverting buffers/line drivers/line receivers are designed to be used with 3-state memory address drivers, clock drivers, and other bus-oriented systems. The HC/HCT 540 are similar in function to the HC/HCT 541 which have noninverting outputs. These devices are characterized for operation over wide temperature ranges to meet industry and military specifications.

## Features

- Low Power consumption characteristic of CMOS devices
- Output drive capability: 15 LS TTL Loads Min.
- Operating speed superior to LS TTL
- Wide operating voltage range: for HC 2 to 6 volts for HCT 4.5 to 5.5 volts
- Low input current:  $1\mu A$  Max.
- Low quiescent current:  $80\mu A$  Max. (74HC)
- High noise immunity characteristic of CMOS
- Diode protection on all inputs

## Logic Diagram

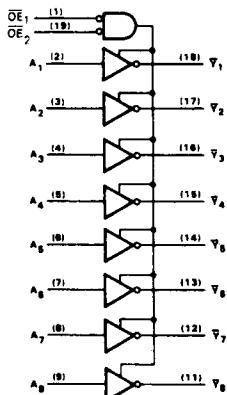
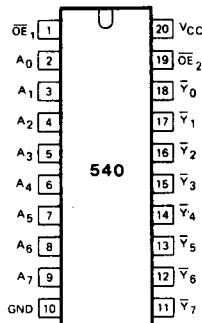


Fig. 1 Logic diagram

## Pin Configuration



Suffix-Blank : Plastic Dual In Line Package  
Suffix-J : Ceramic Dual In Line Package  
Suffix-D : Small Outline Package

## Function Table

INPUTS			OUTPUT
$\overline{OE}_1$	$\overline{OE}_2$	$A_n$	$\overline{Y}_n$
L	L	L	H
L	L	H	L
X	H	X	Z
H	X	X	Z

H = HIGH voltage level

L = LOW voltage level

X = don't care

Z = high impedance OFF state

**Absolute Maximum Ratings**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CC}$	DC Supply voltage		-0.5	+7	V
$I_{IK} I_{OK}$	DC input or output diode current	for $V_I < -0.5$ or $V_I > V_{CC} + 0.5V$		20	mA
$I_O$	DC output source or sink current	for $-0.5V < V_O < V_{CC} + 0.5V$		35	mA
$I_{CC}$	DC $V_{CC}$ or GND current			70	mA
$T_{stg}$	Storage temperature range		-65	150	°C
$P_D$	Power dissipation per package	above +70°C: derate linearly with 8mW/K		500	mW
$T_L$	Lead temperature	At distance $1/16 \pm 1/32$ in. from case for 60 sec(CERAMIC) 10 sec(PLASTIC)		300 260	°C

**Recommended Operating Conditions**

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range $V_{CC}$ : GD54/74HC Types GD54/74HCT Types	2 4.5	6 5.5	V
DC Input or Output Voltage $V_I, V_O$	0	$V_{CC}$	V
Operating Temperature $T_A$ : GD74 Types GD54 Types	-40 -55	+85 +125	°C
Input Rise and Fall times $t_r, t_f$ : GD54/74HC Types at 2V at 4.5V at 6V GD54/74HCT Types at 4.5V		1000 500 400 500	ns

## DC Electrical Characteristics for HC

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HC540		GD54HC540		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V <sub>IH</sub>	HIGH level input Voltage		2.0 4.5 6.0	1.5 3.15 4.2			1.5 3.15 4.2		1.5 3.15 4.2		V
V <sub>IL</sub>	LOW level input voltage		2.0 4.5 6.0			0.3 0.9 1.2		0.3 0.9 1.2		0.3 0.9 1.2	V
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> =-20μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0		1.9 4.4 5.9	1.9 4.4 5.9		V
			I <sub>OH</sub> =-6mA I <sub>OH</sub> =-7.8mA	4.5 6.0	3.98 5.48	4.3 5.2		3.84 5.34	3.7 5.2		
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> =20μA	2.0 4.5 6.0			0.1 0.1 0.1		0.1 0.1 0.1		V
			I <sub>OL</sub> =6mA I <sub>OL</sub> =7.8mA	4.5 6.0		0.17 0.15	0.26 0.26		0.33 0.33		
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0				0.1		1.0		1.0 μA
I <sub>OZ</sub>	Three-State leakage current	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	V <sub>O</sub> =V <sub>CC</sub> or GND	6.0		0.01	0.5		5.0		10.0 μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	6.0				8		80		160 μA

## DC Electrical Characteristics for HCT

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HCT540		GD54HCT540		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
V <sub>IH</sub>	HIGH level input Voltage		4.5 to 5.0	2.0			2.0		2.0		V
V <sub>IL</sub>	LOW level input voltage		4.5 to 5.5				0.8		0.8		V
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> =-20μA	4.5	4.4	4.5		4.4		4.4	V
			I <sub>OH</sub> =-6mA	4.5	3.98	4.3		3.84		3.7	
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> =20μA	4.5			0.1		0.1		V
			I <sub>OL</sub> =6mA	4.5		0.17	0.26		0.33		
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	5.5				0.1		1.0		1.0 μA
I <sub>OZ</sub>	Three-State leakage current	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>IL</sub>	V <sub>O</sub> =V <sub>CC</sub> or GND	5.5		0.01	0.5		5.0		10.0 μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	5.5				8		80		160 μA

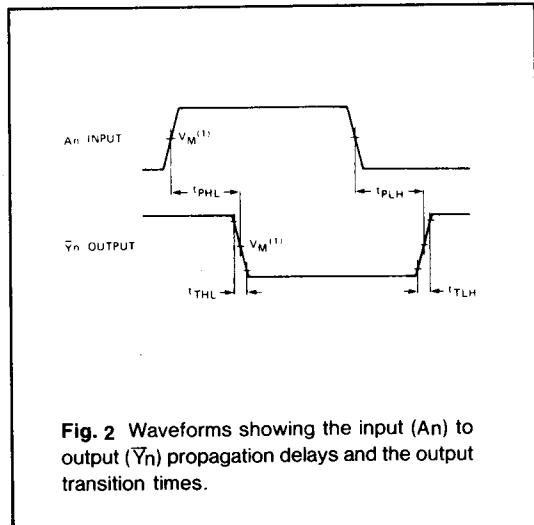
**AC Characteristics for HC:  $t_r=t_f=6\text{ns}$   $C_L=50\text{ pF}$**

SYMBOL	PARAMETER	$V_{CC}$ (V)	$T_A=25^\circ C$			GD74HC540		GD54HC540		UNIT
			MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
$t_{PLH} / t_{PHL}$	Propagation Delay Time $A_n$ to $\bar{Y}_n$	2.0		30	100		120		140	ns
		4.5		9	18		24		28	
		6.0		8	16		20		25	
$t_{PZH} / t_{PZL}$	3-state output Enable Time $\overline{OE}_n$ to $\bar{Y}_n$	2.0		45	140		180		210	ns
		4.5		18	32		40		45	
		6.0		16	28		36		40	
$t_{PLZ} / t_{PHZ}$	3-state Output Disable Time $\overline{OE}_n$ to $\bar{Y}_n$	2.0		45	140		180		210	ns
		4.5		18	32		40		48	
		6.0		16	28		36		42	
$t_{TLH} / t_{THL}$	Output Transition Time	2.0		15	60		75		90	ns
		4.5		6	12		15		18	
		6.0		5	10		13		15	

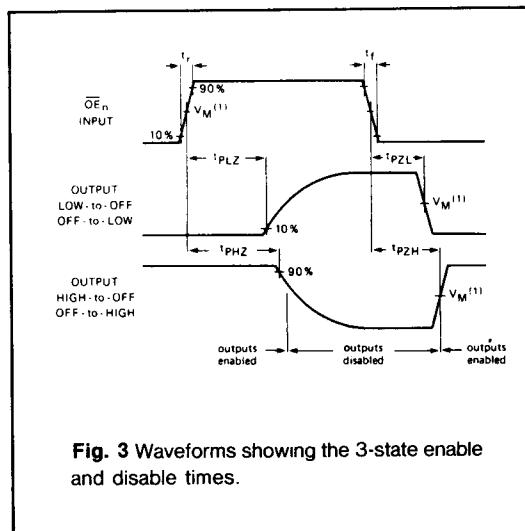
**AC Characteristics for HCT:  $t_r=t_f=6\text{ns}$   $C_L=50\text{ pF}$**

SYMBOL	PARAMETER	$V_{CC}$ (V)	$T_A=25^\circ C$			GD74HCT540		GD54HCT540		UNIT
			MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
$t_{PLH} / t_{PHL}$	Propagation Delay Time $A_n$ to $\bar{Y}_n$	4.5		12	22		26		30	ns
$t_{PZH} / t_{PZL}$	3-state output Enable Time $\overline{OE}_n$ to $\bar{Y}_n$	4.5		19	34		42		48	ns
$t_{PLZ} / t_{PHZ}$	3-state Output Disable Time $\overline{OE}_n$ to $\bar{Y}_n$	4.5		19	34		42		48	ns
$t_{TLH} / t_{THL}$	Output Transition Time	4.5		7	12		15		18	ns

## AC Waveforms



**Fig. 2** Waveforms showing the input ( $A_n$ ) to output ( $\bar{Y}_n$ ) propagation delays and the output transition times.



**Fig. 3** Waveforms showing the 3-state enable and disable times.

### Note to AC waveforms

(1) HC :  $V_M = 50\%$ ;  $V_i = \text{GND to } V_{CC}$ .  
 HCT :  $V_M = 1.3V$ ;  $V_i = \text{GND to } 3V$ .